

## PATENT ABSTRACTS OF JAPAN

(11)Publication number : 07-074340

(43)Date of publication of application : 17.03.1995

(51)Int.Cl.

H01L 27/148

H04N 5/335

H04N 9/07

(21)Application number : 05-217667

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(22)Date of filing : 01.09.1993

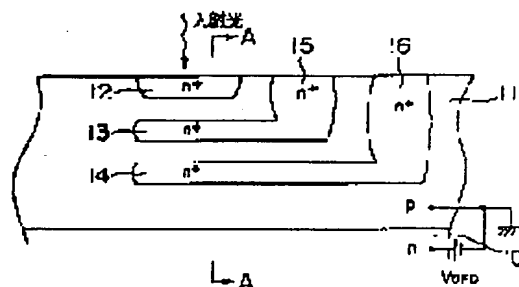
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## (54) SOLID-STATE IMAGE SENSING DEVICE

## (57)Abstract:

PURPOSE: To provide a solid-state image sensing device enhanced in resolution and sensitivity.

CONSTITUTION: A solid-state image sensing device is equipped with photosensitive regions 12, 13, and 14 where signal charge photoelectrically converted on the surface of a P-type semiconductor substrate is stored and a charge transfer register which reads out signal charge stored in the photosensitive regions 12, 13, and 14, wherein the regions 12, 13, and 14 are provided to a semiconductor substrate 10 at different depths from its surface as electrically isolated from each other, and signal charges generated and stored in the photosensitive regions 12, 13, and 14 are separately read out through the charge transfer register.



## LEGAL STATUS

[Date of request for examination]

09.09.1999

[Date of sending the examiner's decision of rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

3220302

[Date of registration]

10.08.2001

[Number of appeal against examiner's decision of rejection]

[Date of requesting appeal against examiner's decision of rejection]

[Date of extinction of right]

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